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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Preferred Device

# **Sensitive Gate Triacs**

# **Silicon Bidirectional Thyristors**

Designed for use in solid state relays, MPU interface, TTL logic and other light industrial or consumer applications. Supplied in surface mount package for use in automated manufacturing.

#### **Features**

- Sensitive Gate Trigger Current in Four Trigger Modes
- Blocking Voltage to 600 Volts
- Glass Passivated Surface for Reliability and Uniformity
- Surface Mount Package
- Pb-Free Packages are Available

#### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Note 1) (Sine Wave, 50 to 60 Hz, Gate Open, T <sub>J</sub> = 25 to 110°C) MAC08BT1 MAC08MT1	V <sub>DRM,</sub> V <sub>RRM</sub>	200 600	V
On-State Current RMS (T <sub>C</sub> = 80°C) (Full Sine Wave 50 to 60 Hz)	I <sub>T(RMS)</sub>	0.8	Α
Peak Non-repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T <sub>C</sub> = 25°C)	I <sub>TSM</sub>	8.0	Α
Circuit Fusing Considerations (Pulse Width = 8.3 ms)	I <sup>2</sup> t	0.4	A <sup>2</sup> s
Peak Gate Power $(T_C = 80^{\circ}C, \text{ Pulse Width } \leq 1.0 \mu\text{s})$	P <sub>GM</sub>	5.0	W
Average Gate Power (T <sub>C</sub> = 80°C, t = 8.3 ms)	P <sub>G(AV)</sub>	0.1	W
Operating Junction Temperature Range	TJ	-40 to +110	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

 V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient PCB Mounted per Figure 1	$R_{\theta JA}$	156	°C/W
Thermal Resistance, Junction-to-Tab Measured on MT2 Tab Adjacent to Epoxy	$R_{\theta JT}$	25	°C/W
Maximum Device Temperature for Soldering Purposes for 10 Secs Maximum	T <sub>L</sub>	260	°C



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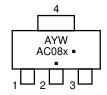
# TRIAC 0.8 AMPERE RMS 200 thru 600 VOLTS



#### MARKING DIAGRAM



SOT-223 CASE 318E STYLE 11



A = Assembly Location

Y = Year W = Work Week AC08X = Device Code x= B or M

= Pb–Free Package

(Note: Microdot may be in either location)

PIN ASSIGNMENT				
1	Main Terminal 1			
2	Main Terminal 2			
3	Gate			
4	Main Terminal 2			

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MAC08BT1	SOT-223	1000 Tape & Reel
MAC08BT1G	SOT-223 (Pb-Free)	1000 Tape & Reel
MAC08MT1	SOT-223	1000 Tape & Reel
MAC08MT1G	SOT-223 (Pb-Free)	1000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

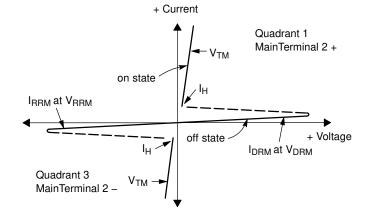
#### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted; Electricals apply in both directions.)

Characteristic			Min	Тур	Max	Unit
OFF CHARACTERISTICS		•	•	•		
Peak Repetitive Blocking Current $(V_D = Rated V_{DRM}, V_{RRM}; Gate Open)$	T <sub>J</sub> = 25°C T <sub>J</sub> = 110°C	I <sub>DRM</sub> , I <sub>RRM</sub>	- -	_ _	10 200	μ <b>Α</b> μ <b>Α</b>
ON CHARACTERISTICS						
Peak On-State Voltage (Note 2) (I <sub>T</sub> = ± 1.1 A Peak)		V <sub>TM</sub>	-	_	1.9	V
Gate Trigger Current (Continuous dc) All Quadrants ( $V_D = 12 \text{ Vdc}, R_L = 100 \Omega$ )		lgт	-	_	10	mA
Holding Current (Continuous dc) $(V_D = 12 \text{ Vdc}, \text{ Gate Open, Initiating Current} = \pm 20 \text{ mA})$		I <sub>H</sub>	-	_	5.0	mA
Gate Trigger Voltage (Continuous dc) All Quadrants ( $V_D = 12 \text{ Vdc}, R_L = 100 \Omega$ )		V <sub>GT</sub>	-	_	2.0	V
DYNAMIC CHARACTERISTICS						
Critical Rate of Rise of Commutation Voltage (f = 250 Hz, $I_{TM}$ = 1.0 A, Commutating di/dt = 1.5 A/mS On–State Current Duration = 2.0 mS, $V_{DRM}$ = 200 V, Gate Unenergized, $T_{C}$ = 110°C, Gate Source Resistance = 150 $\Omega$ , See Figure 10)		(dv/dt) <sub>c</sub>	1.5	_	-	V/µs
Critical Rate-of-Rise of Off State Voltage (V <sub>pk</sub> = Rated V <sub>DRM</sub> , T <sub>C</sub> = 110°C, Gate Open, Exponential Method	dv/dt	10	_	-	V/μs	

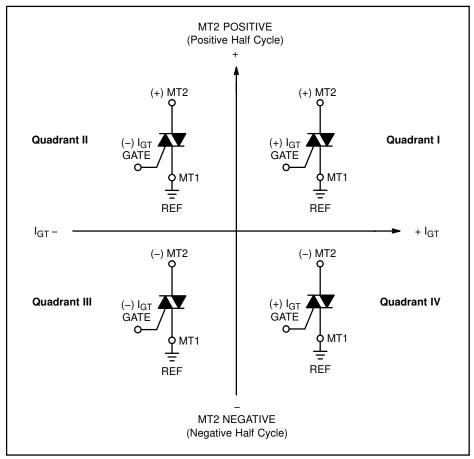
<sup>2.</sup> Pulse Test: Pulse Width ≤ 300 μsec, Duty Cycle ≤2%.

# Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
V <sub>DRM</sub>	Peak Repetitive Forward Off State Voltage
I <sub>DRM</sub>	Peak Forward Blocking Current
V <sub>RRM</sub>	Peak Repetitive Reverse Off State Voltage
I <sub>RRM</sub>	Peak Reverse Blocking Current
V <sub>TM</sub>	Maximum On State Voltage
I <sub>H</sub>	Holding Current



#### **Quadrant Definitions for a Triac**



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

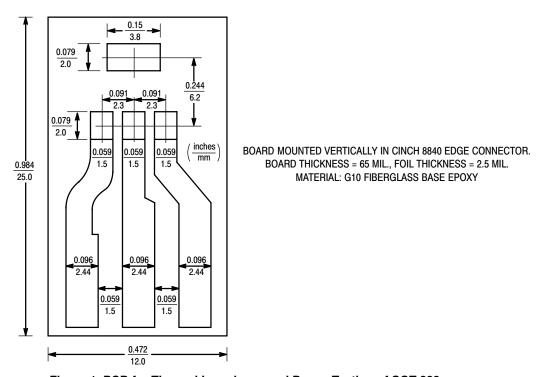


Figure 1. PCB for Thermal Impedance and Power Testing of SOT-223

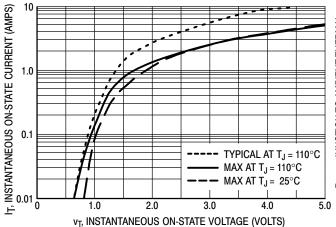


Figure 2. On-State Characteristics

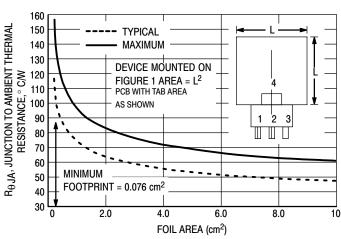


Figure 3. Junction to Ambient Thermal Resistance versus Copper Tab Area

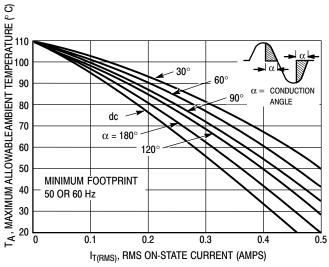


Figure 4. Current Derating, Minimum Pad Size Reference: Ambient Temperature

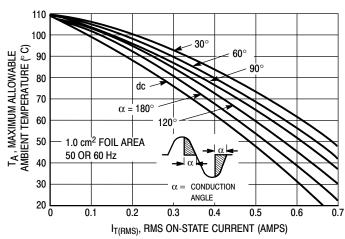


Figure 5. Current Derating, 1.0 cm Square Pad Reference: Ambient Temperature

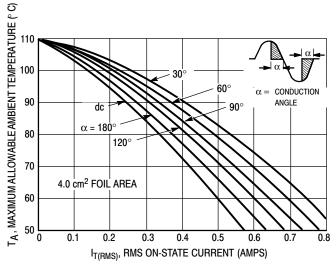


Figure 6. Current Derating, 2.0 cm Square Pad Reference: Ambient Temperature

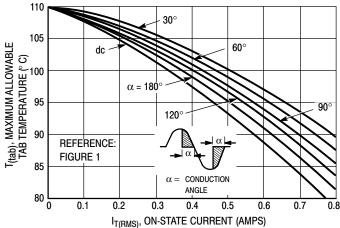


Figure 7. Current Derating Reference: MT2 Tab

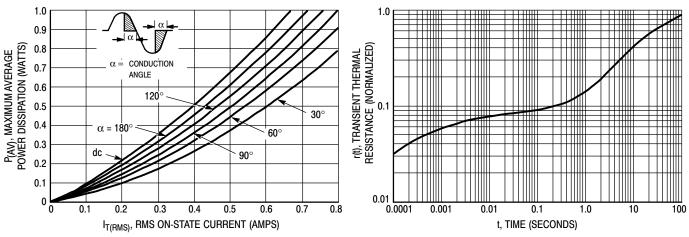


Figure 8. Power Dissipation

Figure 9. Thermal Response, Device Mounted on Figure 1 Printed Circuit Board

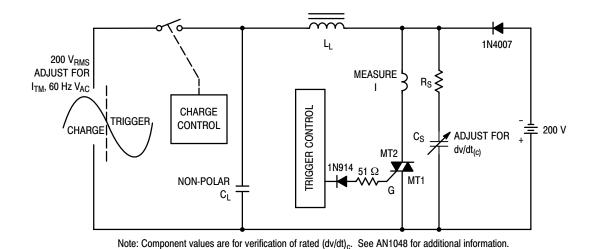


Figure 10. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Voltage (dv/dt)<sub>c</sub>

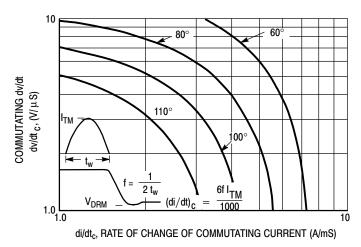


Figure 11. Typical Commutating dv/dt versus Current Crossing Rate and Junction Temperature

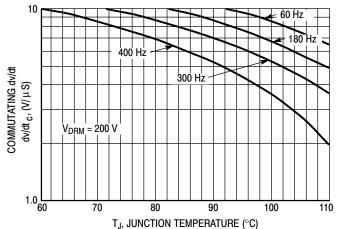


Figure 12. Typical Commutating dv/dt versus Junction Temperature at 0.8 Amps RMS

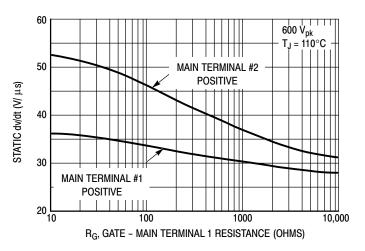
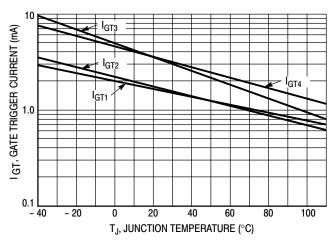


Figure 13. Exponential Static dv/dt versus Gate – Main Terminal 1 Resistance



**Figure 14. Typical Gate Trigger Current Variation** 

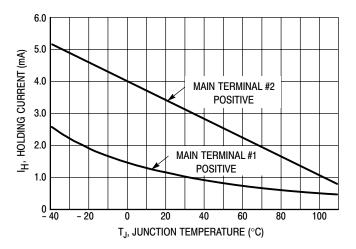


Figure 15. Typical Holding Current Variation

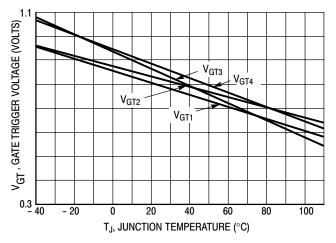
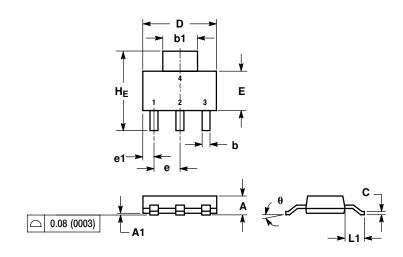


Figure 16. Gate Trigger Voltage Variation

#### PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUE L



#### NOTES:

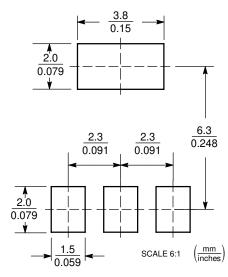
- 1. DIMENOIS Y14.5M, 1982. DIMENSIONING AND TOLERANCING PER ANSI
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
A	0°	_	10°	0°	_	10°

#### STYLE 11:

- PIN 1. MT 1
- 2. MT 2 3. GATE

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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